L	Hits	Search Text	DB	Time stamp
Number				
51	49479	(GaAs (gallium near arseni\$3)) with	USPAT;	2004/09/27
	101.5	(substrate wafer)	US-PGPUB;	16:24
		(1	EPO; JPO;	
			DERWENT;	
		,	IBM TDB	
52	1227	((ZnSe ("Zn.sub."\$4"Se.sub."\$4)) and	USPAT;	2004/09/27
		(ZnTe ("Zn.sub."\$4"Te.sub."\$4)))	US-PGPUB;	16:28
		ZnSe/ZnTe	EPO; JPO;	10.20
			DERWENT;	
			IBM TDB	1
54	7398	ZnMqSSe	USPAT;	2004/09/27
33	, 550	("Zn.sub."\$6"Mg.sub."\$6"S.sub."\$6"Se.sub."		16:31
		ZnSSe ("Zn.sub."\$6"S.sub."\$6"Se.sub."\$6)	EPO; JPO;	10.51
		(Zn"S.sub."\$6"Se.sub."\$6) SnMgSe	DERWENT;	
		("Zn.sub."\$6"Mg.sub."\$6"Se.sub."\$6)	IBM TDB	
		(Zn"Mg.sub. "\$6"Se.sub. "\$6) ZnSe	1011_100	
55	415	((GaAs (gallium near arseni\$3)) with	USPAT;	2004/09/27
	113	(substrate wafer)) and (((ZnSe	US-PGPUB;	16:32
		("Zn.sub."\$4"Se.sub."\$4)) and (ZnTe	EPO; JPO;	10.32
		("Zn.sub."\$4"Te.sub."\$4))) ZnSe/ZnTe) and	DERWENT;	
		(ZnMqSSe	IBM TDB	ļ
		("Zn.sub."\$6"Mg.sub."\$6"S.sub."\$6"Se.sub."		
		ZnSSe ("Zn.sub."\$6"S.sub."\$6"Se.sub."\$6)	۲۰۰	
		(Zn"S.sub. "\$6"Se.sub. "\$6) SnMqSe		
		("Zn.sub."\$6"Mg.sub."\$6"Se.sub."\$6)		
		(Zn"Mg.sub."\$6"Se.sub."\$6) ZnSe)		
56	35	(((GaAs (gallium near arseni\$3)) with	USPAT;	2004/09/27
30	33	(substrate wafer)) and (((ZnSe	US-PGPUB;	16:32
		("Zn.sub."\$4"Se.sub."\$4)) and (ZnTe	EPO; JPO;	16.32
		("Zn.sub."\$4"Te.sub."\$4))) ZnSe/ZnTe) and	DERWENT;	
		(ZnMgSSe	IBM TDB	
		("Zn.sub."\$6"Mg.sub."\$6"S.sub."\$6"Se.sub."		
		ZnSSe ("Zn.sub."\$6"S.sub."\$6"Se.sub."\$6)	γο,	
		(Zn"S.sub."\$6"Se.sub."\$6) SnMqSe		
		("Zn.sub."\$6"Mq.sub."\$6"Se.sub."\$6)		
		(Zn.Sub. 36 Mg.Sub. 36 Se.Sub. 36) (Zn.Mg.sub."\$6"Se.sub."\$6) ZnSe)) and		1
		(ZN Mg.Sub. 30 Se.Sub. 30) ZNSe)) and photodiode		[
	L	photoaroue .	l	<u> </u>